## NSN 5961-00-092-0518



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-092-0518 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact **Internal Junction Configuration:** Pnp **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -60.0 breakdown voltage, collector-to-base, emitter open and -60.0 breakdown voltage, collector-to-emitter, base open and -70.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and -5.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** -100.00 milliamperes base current, dc and -500.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 1.4 watts collector power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Design analysis; junction pattern arrangement: pnp **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life:

No

N/a

**Unit Of Measure:** 

**Demilitarization:** 

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